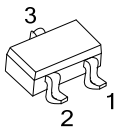
BAV70W

DIODE

DUAL SURFACE MOUNT SWITCHING DIODE



SOT-323

■ DESCRIPTION

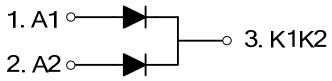
The UTC **BAV70W** is a dual surface mount switching diode providing the designers high switching speed, high conductance and high reliability.

The UTC **BAV70W** is suitable for common switching applications.

■ FEATURES

* High Switching Speed
* High Conductance
* High Reliability
* Green Product

■ SYMBOL



■ ORDERING INFORMATION

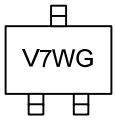
Ordering Number	Package	Pin Assignment			Packing
		1	2	3	
BAV70WG-AL3-R	SOT-323	A1	A2	K1K2	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode

BAV70WG-AL3-R
(1)Packing Type
(2)Package Type
(3)Green Package

(1) R: Tape Reel
(2) AL3 : SOT-323
(3) G: Halogen Free and Lead Free

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Non-Repetitive Reverse Voltage		V_{RM}	100	V
Peak Repetitive Reverse Voltage		V_{RRM}	75	V
Working Peak Reverse Voltage		V_{RWM}	75	V
DC Blocking Voltage		V_R	75	V
RMS Reverse Voltage		$V_{R(RMS)}$	53	V
Forward Continuous Current		I_{FM}	300	mA
Average Rectified Output Current		I_O	150	mA
Non-Repetitive Peak Forward Surge Current	@ t = 1.0μs	I_{FSM}	2.0	A
	@ t = 1.0s		1.0	
Power Dissipation		P_D	200	mW
Operating Temperature		T_J	-65~+150	°C
Storage Temperature		T_{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Thermal Resistance Junction to Ambient Air	θ_{JA}	625	°C/W

■ ELECTRICAL CHARACTERISTICS (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note)	$V_{(BR)R}$	I_R= 100μA	75			V
Forward Voltage	V_F	I_F= 1.0mA			0.715	V
		I_F= 10mA			0.855	
		I_F= 50mA			1.0	
		I_F= 150mA			1.25	
Reverse Current (Note 1)	I_R	V_R= 75V			2.5	μA
		V_R= 75V, T_J= 150°C			50	
		V_R= 25V, T_J= 150°C			30	
		V_R=20V			25	nA
Total Capacitance	C_T	V_R= 0, f = 1.0MHz			2.0	pF
Reverse Recovery Time	t_{rr}	I_F= I_R= 10mA, I_{rr} = 0.1 x I_R, R_L= 100Ω			4.0	ns

Notes: Short duration test pulse used to minimize self-heating effect.

■ TYPICAL CHARACTERISTICS